


## APPLICATION DATA SHEET

Electronic Version v14

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<b>Title of Invention</b>	[LOW TEMPERATURE POLYSILICON THIN FILM TRANSISTOR AND METHOD OF FORMING POLYSILICON LAYER OF SAME]		
Application Type : regular, utility Attorney Docket Number : 10957-US-PA			
Correspondence address: Customer Number: 31561 			
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as our attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.